

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

2SC3324

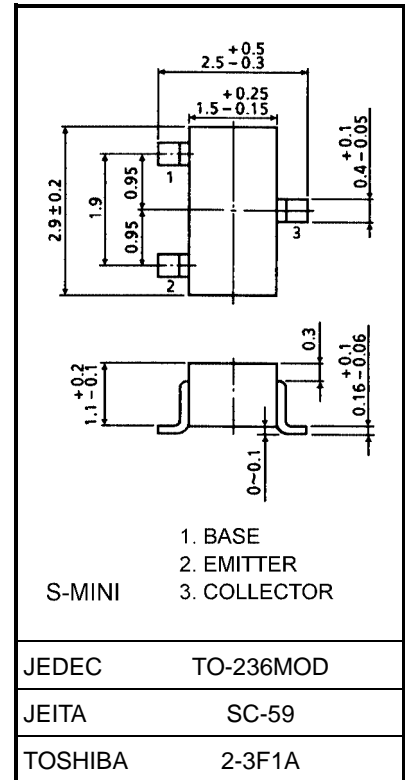
Audio Frequency Low Noise Amplifier Applications

- High voltage: $V_{CEO} = 120\text{ V}$
- Excellent h_{FE} linearity: $h_{FE}(I_C = 0.1\text{ mA}) / h_{FE}(I_C = 2\text{ mA}) = 0.95$ (typ.)
- High h_{FE} : $h_{FE} = 200\sim 700$
- Low noise: $NF(2) = 0.2\text{ dB}$ (typ.), 3 dB (max)
- Complementary to 2SA1312
- Small package

Maximum Ratings ($T_a = 25^\circ\text{C}$)

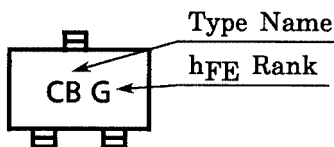
Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	120	V
Collector-emitter voltage	V_{CEO}	120	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_C	100	mA
Base current	I_B	20	mA
Collector power dissipation	P_C	150	mW
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55~125	$^\circ\text{C}$

Unit: mm



Weight: 0.012 g (typ.)

Marking

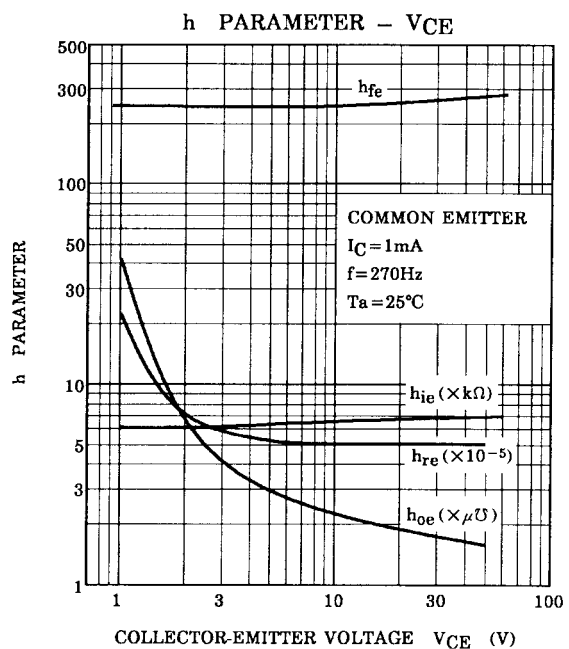
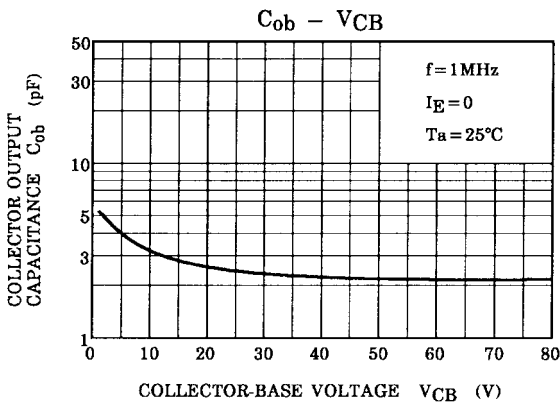
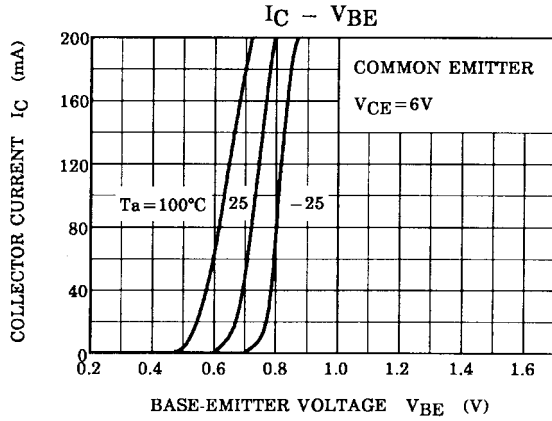
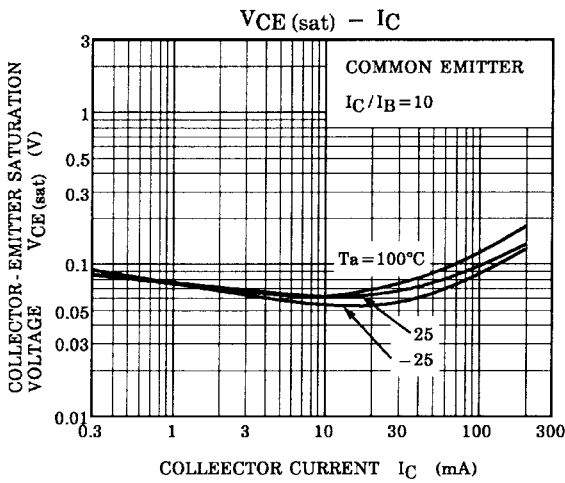
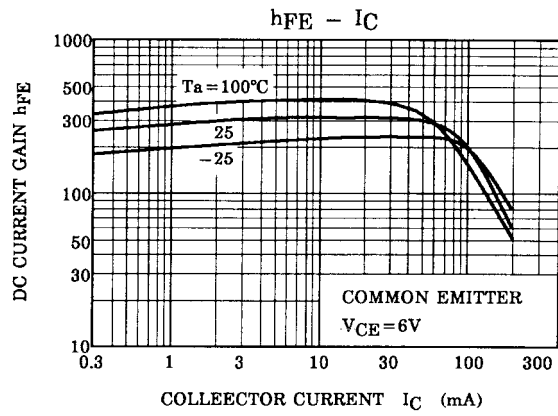
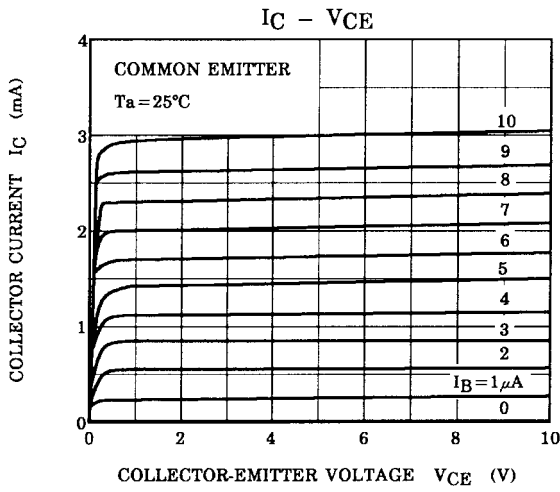


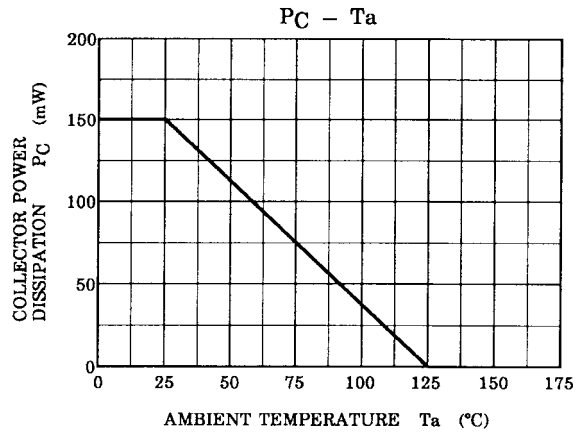
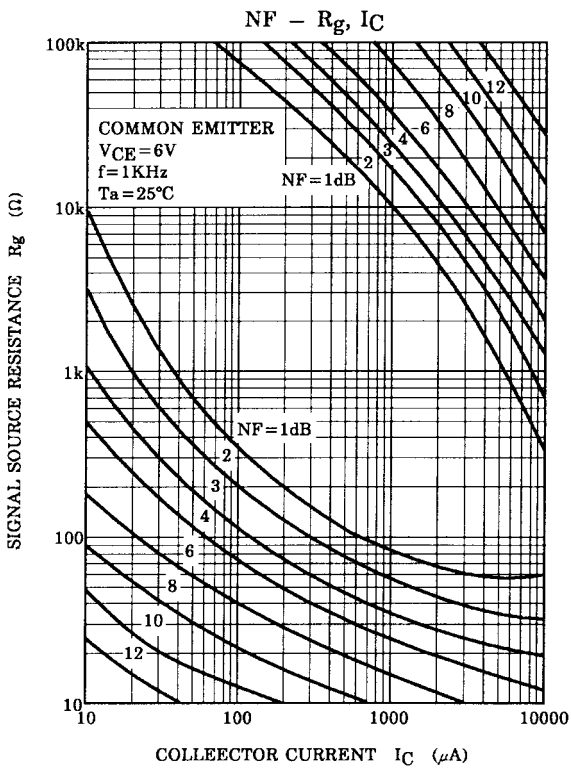
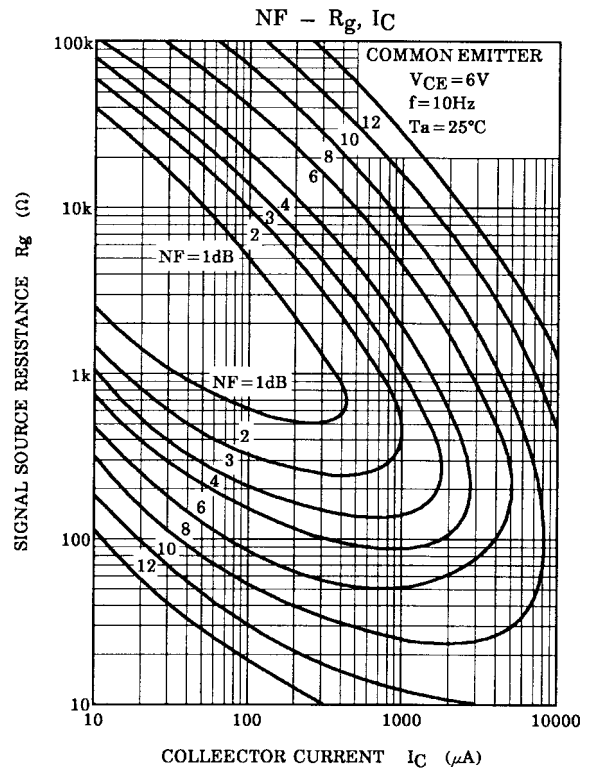
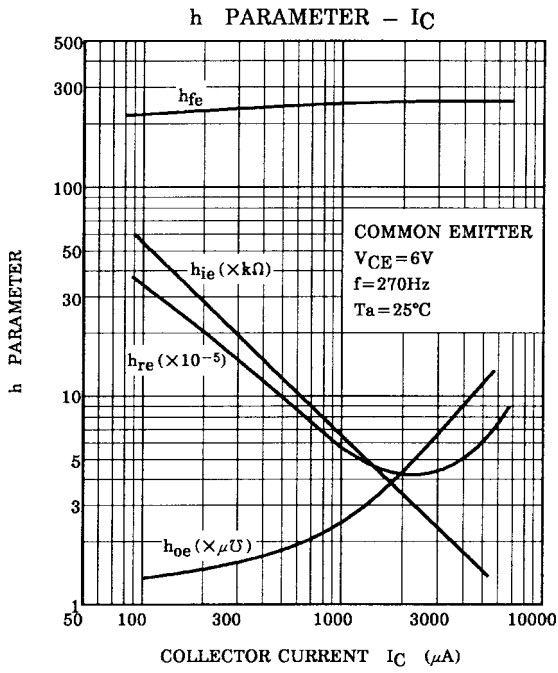
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = 120\text{ V}, I_E = 0$	—	—	0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 5\text{ V}, I_C = 0$	—	—	0.1	μA
DC current gain	h_{FE} (Note)	$V_{CE} = 6\text{ V}, I_C = 2\text{ mA}$	200	—	700	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 10\text{ mA}, I_B = 1\text{ mA}$	—	—	0.3	V
Transition frequency	f_T	$V_{CE} = 6\text{ V}, I_C = 1\text{ mA}$	—	100	—	MHz
Collector output capacitance	C_{ob}	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	4	—	pF
Noise figure	NF (1)	$V_{CB} = 6\text{ V}, I_C = 0.1\text{ mA}, f = 100\text{ Hz},$ $R_g = 10\text{ k}\Omega$	—	0.5	6	dB
	NF (2)	$V_{CB} = 6\text{ V}, I_C = 0.1\text{ mA}, f = 1\text{ kHz},$ $R_g = 10\text{ k}\Omega$	—	0.2	3	

Note: h_{FE} classification GR (G): 200~400, BL (L): 350~700

() marking symbol





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